









 	<h2 style="color: red;">FQB34N20TM_AM002</h2> <p>Hersteller-Teilenummer: FQB34N20TM_AM002</p> <p>Hersteller / Marke: Fairchild/ON Semiconductor</p> <p>Teil der Beschreibung: FQB34N20TM_AM002 Fairchild/ON Semiconductor</p> <p>Datenblätter:  FQB34N20TM_AM002.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 32363 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
	
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	FQB34N20TM_AM002
Hersteller	Fairchild/ON Semiconductor
Beschreibung	FQB34N20TM_AM002 Fairchild/ON Semiconductor
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	32363 pcs Stock
Serie	QFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D ² PAK (TO-263AB)
Verlustleistung (max)	3.13W (Ta), 180W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	200V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	31A (Tc)
Rds On (Max) @ Id, Vgs	75 mOhm @ 15.5A, 10V
VGS (th) (Max) @ Id	5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	3100pF @ 25V
Antriebsspannung (Max Rds On, Min Rds On)	10V
Vgs (Max)	±30V
Verpackung	Original-Reel®
















































FQB34N20TM_AM002 ist neu im Original, Suche FQB34N20TM_AM002 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie FQB34N20TM_AM002 Fairchild/ON Semiconductor mit Garantie und Vertrauen. Anfrage FQB34N20TM_AM002: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>FQB34P10TM-F085P AMI Semiconductor / ON Semiconductor PMOS D2PAK 100V 60 MOHM</p>	 <p>FQB34P10TM Fairchild/ON Semiconductor MOSFET P-CH 100V 33.5A D2PAK</p>	 <p>FQB34N20LTM AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A D2PAK</p>	 <p>FQB34P10TM AMI Semiconductor / ON Semiconductor MOSFET P-CH 100V 33.5A D2PAK</p>
 <p>FQB34N20TM FAIRCHILD FQB34N20TM FAIRCHILD</p>	 <p>FQB34N20TM-AM002 AMI Semiconductor / ON Semiconductor MOSFET N-CH 200V 31A D2PAK</p>	 <p>FQB34N20LTM Fairchild/ON Semiconductor MOSFET N-CH 200V 31A D2PAK</p>	 <p>FQB34N20L FAIRCHI FQB34N20L FAIRCHI</p>

heiße Teile

Mehr

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|--|---|--|---|--|
|  FQB30N06 |  FQB30N06L |  FQB30N06LTM |  FQB30N06LTM |  FQB30N06TM |
|  FQB30N06TM |  FQB32N12V2 |  FQB32N12V2TM |  FQB32N12V2TM |  FQB32N20 |
|  FQB32N20C |  FQB32N20CTM |  FQB32N20CTM |  FQB32N30 |  FQB33N10 |
|  FQB33N10L |  FQB33N10LTM |  FQB33N10LTM |  FQB33N10TM |  FQB33N10TM |
|  FQB34N20 |  FQB34N20L |  FQB34N20LTM |  FQB34N20LTM |  FQB34N20TM |
|  FQB34P10 |  FQB34P10TM |  FQB34P10TM |  FQB34P10TM_F085 |  FQB3N25TM |
|  FQB3N25TM |  FQB3N30TM |  FQB3N30TM |  FQB3N40TM |  FQB3N40TM |
|  FQB3N60C |  FQB3N80TM |  FQB3N80TM |  FQB3N90TM |  FQB3N90TM |
|  FQB3P20TM |  FQB3P20TM |  FQB3P50TM |  FQB3P50TM |  FQB44N10 |
|  FQB44N10TM |  FQB44N10TM |  FQB46N15 |  FQB46N15TM |  FQB47P06 |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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